Low Power 48MHz Oscillator for Intel Bay Trail Platform



Features

■ Frequency: 48MHz ■ Stability: 50 PPM ■ Supply voltage: 3.3V

■ Operating temperature range: I-temp (-40°C to 85°C)

■ LVCMOS/HCMOS compatible output

■ Packages: SOT23, 2.5x2.0mmxmm, 5.0x3.2mmxmm, 7.0x5.0mmxmm

■ 100% pin-to-pin drop-in replacement to quartz-based XO

■ Pb-free, RoHS and REACH compliant

Applications

■ Oscillator for Intel Bay Trail Super IO IC







Electrical Characteristics^[1]

Symbol	Min.	Тур.	Max.	Unit	Condition	
Frequency Range						
f		48		MHz		
Frequency Stability and Aging						
F_stab	-50	-	+50	PPM	Inclusive of Initial tolerance at 25°C, 1st year aging at 25°C, and variations over operating temperature, rated power supply	
		Operati	ng Tempera	ture Range		
T_use	-40	_	+85	°C	Extended Commercial	
	Sı	ipply Voltag	e and Curr	ent Consum	ption	
Vdd	2.97	3.3	3.63	V		
ldd	_	4.3	5.0	mA	No load condition	
I_OD	_	_	4	mA	OE = GND, output is Weakly Pulled Down	
I_std	_	2.6	4.3	μΑ	ST = GND, Output is Weakly Pulled Down	
		LVCMOS	Output Ch	aracteristics	S	
DC	45	-	55	%		
Tr, Tf	_	_	2	ns	20% - 80%	
VOH	90%	_	_	Vdd	IOH = -4 mA	
VOL	_	_	10%	Vdd	IOL = 4 mA	
		Inp	ut Characte	ristics		
VIH	70%	_	_	Vdd	Pin 1, OE or ST	
VIL	_	_	30%	Vdd	Pin 1, OE or ST	
Z_in	_	87	100	kΩ	Pin 1, OE logic high or logic low, or ST logic high	
	2	_	-	ΜΩ	Pin 1, ST logic low	
		Startu	and Resu	ne Timing		
T_start	_	-	5	ms	Measured from the time Vdd reaches its rated minimum value	
T_oe	_	_	130	ns		
T_resume	_	_	5	ms	Measured from the time ST pin crosses 50% threshold	
Jitter						
T_jitt	_	1.76	3	ps		
T_phj	_	0.5	0.9	ps	Integration bandwidth = 900 kHz to 7.5 MHz	
	f F_stab Vdd Idd I_OD I_std DC Tr, Tf VOH VOL VIH VIL Z_in T_start T_oe T_resume T_jitt	F_stab	F 48 Frequer F_stab -50 - Operation T_use -40 - Supply Voltage Vdd 2.97 3.3 Idd - 4.3 I_OD I_std - 2.6 LVCMOS DC 45 - Tr, Tf VOH 90% - VOL VIH 70% - VIL Z_in - 87 2 - Startup T_start T_oe T_resume T_jitt - 1.76	Frequency R	Frequency Range f	

990 Almanor Avenue Sunnyvale, CA 94085 (408) 328-4400 www.sitime.com Rev. 1.1 Revised August 29, 2013

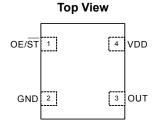
^{1.} All electrical specifications in the above table are specified with 15 pF output load, 3.3V VDD and 48MHz output frequency unless otherwise stated.

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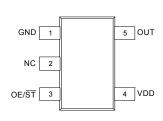
Pin Description (4-Pin Devices)

Pin	Symbol		Functionality
	OE/ ST	Output Enable	H or Open ^[2] : specified frequency output L: output is high impedance. Only output driver is disabled.
1		Standby	H or Open ^[2] : specified frequency output L: output is low (weak pull down). Device goes to sleep mode. Supply current reduces to I_std.
2	GND	Power	Electrical ground ^[3]
3	OUT	Output	Oscillator output
4	VDD	Power	Power supply voltage ^[3]



Pin Description (5-Pin SOT23 Device)

Pin	Symbol	Functionality		
1	GND	Power	Electrical ground ^[3]	
2	NC	No Connect	No connect	
		Output Enable	H or Open ^[2] : specified frequency output L: output is high impedance. Only output driver is disabled.	
3	OE/ST	Standby	H or Open ^[4] : specified frequency output L: output is low (weak pull down). Device goes to sleep mode. Supply current reduces to I_std.	
4	VDD	Power	Power supply voltage ^[3]	
5	OUT	Output	Oscillator output	



Top View

Notes:

- 2. A pull-up resistor of <10 k Ω between OE/ $\overline{\text{ST}}$ pin and Vdd is recommended in high noise environment. 3. A capacitor value of 0.1 μF between Vdd and GND is recommended.

Absolute Maximum

Attempted operation outside the absolute maximum ratings of the part may cause permanent damage to the part. Actual performance of the IC is only guaranteed within the operational specifications, not at absolute maximum ratings.

Parameter	Min.	Max.	Unit
Storage Temperature	-65	150	°C
VDD	-0.5	4	V
Electrostatic Discharge	-	2000	V
Soldering Temperature (follow standard Pb free soldering guidelines)	-	260	°C
Junction Temperature	-	150	°C

Thermal Consideration

Package	θJA, 4 Layer Board (°C/W)	θJC, Bottom (°C/W)
SOT23	420	174
2520	117	26
3225	109	27
5032	97	24
7050	191	30

Environmental Compliance

Parameter	Condition/Test Method
Mechanical Shock	MIL-STD-883F, Method 2002
Mechanical Vibration	MIL-STD-883F, Method 2007
Temperature Cycle	JESD22, Method A104
Solderability	MIL-STD-883F, Method 2003
Moisture Sensitivity Level	MSL1 @ 260°C



Test Circuit and Waveform^[4]

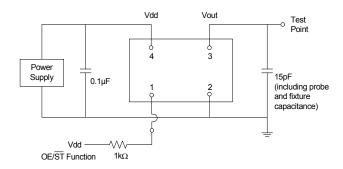


Figure 1. Test Circuit

Note:

4. Duty Cycle is computed as Duty Cycle = TH/Period.

50% 20% Vdd High Pulse Low Pulse (TH) Period

Figure 2. Waveform

Timing Diagram

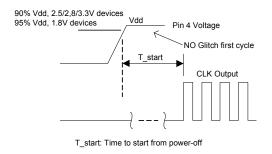


Figure 3. Startup Timing (OE/ST Mode)

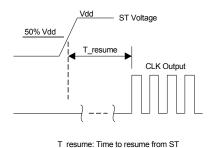
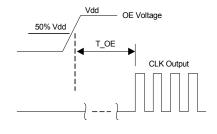
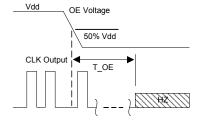


Figure 4. Standby Resume Timing (ST Mode Only)





T_OE: Time to put the output drive in High Z mode

Figure 5. OE Enable Timing (OE Mode Only)

T_OE: Time to re-enable the clock output

Figure 5. OE Disable Timing (OE Mode Only)

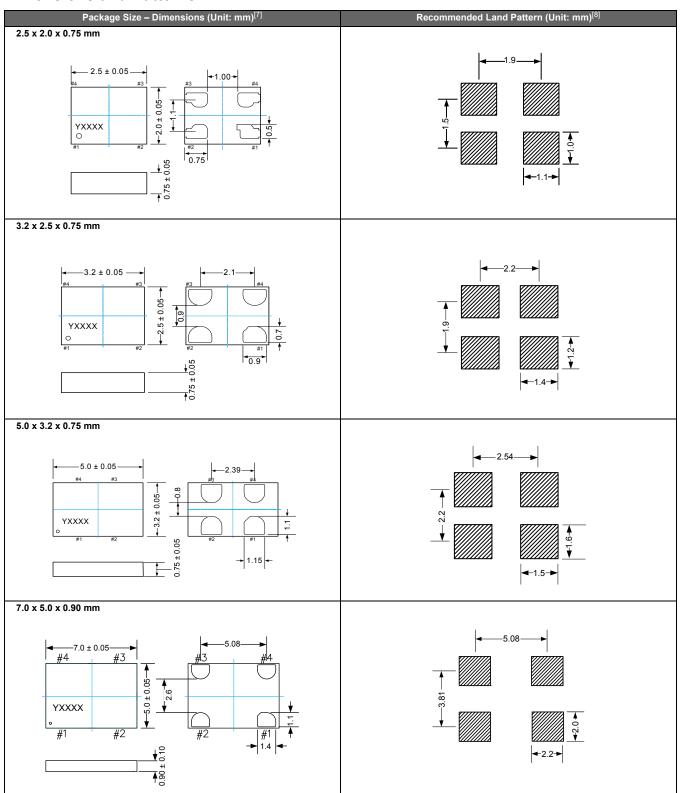
Notes:

- 5. SiT1602 supports no runt pulses and no glitches during startup or resume.
- 6. SiT1602 supports gated output which is accurate within rated frequency stability from the first cycle.

Low Power 48MHz Oscillator for Intel Bay Trail



Dimensions and Patterns



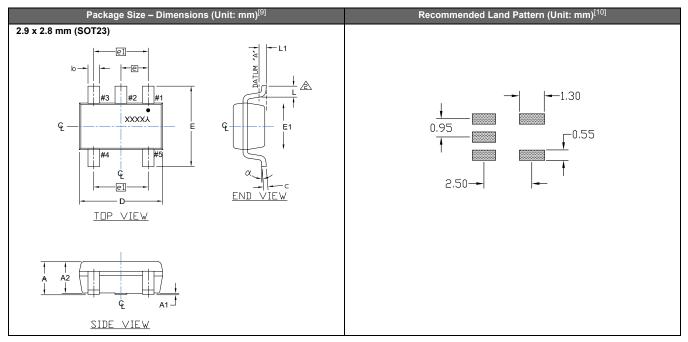
7. Top marking: Y denotes manufacturing origin and XXXX denotes manufacturing lot number. The value of "Y" will depend on the assembly location of the device.

8. A capacitor of value 0.1 µF between Vdd and GND is recommended.

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Dimensions and Patterns



Notes

9.Top marking: Y denotes manufacturing origin and XXXX denotes manufacturing lot number. The value of "Y" will depend on the assembly location of the device.

10. A capacitor of value 0.1 µF between Vdd and GND is recommended.

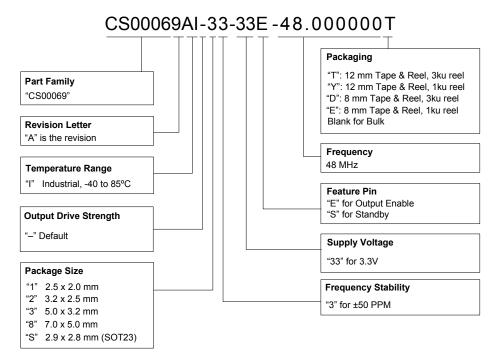
Dimension Table (SOT23)

Symbol	Min.	Nom.	Max.	
Α	0.90	1.27	1.45	
A1	0.00	0.07	0.15	
A2	0.90	1.2	1.30	
b	0.30	0.35	0.50	
С	0.14	0.153	0.20	
D		2.90		
Е	2.80			
E1	1.60			
е		0.95		
e1		1.90		
L	0.30	0.38	0.55	
L1		0.25		
а	0°	-	8°	

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Ordering Information



Ordering Codes for Supported Tape & Reel Packing Method^[11]

Device Size	8 mm T&R (3ku)	8 mm T&R (1ku)	12 mm T&R (3ku)	12 mm T&R (1ku)
2.5 x 2.0 mm	D	E	-	-
3.2 x 2.5 mm	D	E	-	-
5.0 x 3.2 mm	-	-	Т	Y
7.0 x 5.0 mm	-	-	-	-
2.9 x 2.8 mm	D	E	-	-

Note:

11. For "-", contact SiTime for availability.

Additional Information

Document	Description	Download Link	
Time Machine II	MEMS oscillator programmer	http://www.sitime.com/support/time-machine-oscillator-programmer	
Field Programmable Oscillators	Devices that can be programmable in the field by Time Machine II	http://www.sitime.com/products/field-programmable-oscillators	
Manufacturing Notes	Tape & Reel dimension, reflow profile and other manufacturing related info	http://www.sitime.com/component/docman/doc_download/85-manu facturing-notes-for-sitime-oscillators	
Qualification Reports	RoHS report, reliability reports, composition reports	http://www.sitime.com/support/quality-and-reliability	
Performance Reports	Additional performance data such as phase noise, current consumption and jitter for selected frequencies	http://www.sitime.com/support/performance-measurement-report	
Termination Techniques	Termination design recommendations	http://www.sitime.com/support/application-notes	
Layout Techniques	Layout recommendations	http://www.sitime.com/support/application-notes	

SiT1602

Low Power, Standard Frequency Oscillator



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